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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/502,055	07/30/2004	Takunori Taira	256740US2PCT	2509
	590 01/08/2007 AK, MCCLELLAND, M	MAIER & NEUSTADT, P.C.	EXAM	INER
1940 DUKE STREET ALEXANDRIA, VA 22314			. NGUYEN, TUAN N	
ALEXANDICA	, VA 22314	ART UNIT PAPER NUMBER		
			2828	
SHORTENED STATUTORY	PERIOD OF RESPONSE	MAIL DATE	DELIVERY MODE	
3 MONTHS 01/0		01/08/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

		Application No.	Applicant(s)
		10/502,055	TAIRA ET AL.
	Office Action Summary	Examiner	Art Unit
		Tuan N. Nguyen	2828
Period fo	The MAILING DATE of this communication app or Reply	ears on the cover sheet with the c	orrespondence address
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DANSIONS of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. It is period for reply is specified above, the maximum statutory period we re to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from , cause the application to become ABANDONEI	J. lely filed the mailing date of this communication. D (35 U.S.C. § 133).
Status			
1)⊠ 2a)□ 3)□	Responsive to communication(s) filed on <u>27 Sec</u> This action is FINAL . 2b) This Since this application is in condition for allower closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro	
Dispositi	ion of Claims		•
5)□ 6)⊠ 7)□ 8)□ Applicat i	Claim(s) 4-12 is/are pending in the application. 4a) Of the above claim(s) is/are withdraw Claim(s) is/are allowed. Claim(s) 4-12 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or ion Papers The specification is objected to by the Examine	vn from consideration. r election requirement. r.	
	The drawing(s) filed on 30 July 2004 is/are: a) Applicant may not request that any objection to the case Replacement drawing sheet(s) including the correction of the oath or declaration is objected to by the Ex	drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).
Priority ι	ınder 35 U.S.C. § 119		
a)[Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the prior application from the International Bureau see the attached detailed Office action for a list of	s have been received. s have been received in Application ity documents have been receive (PCT Rule 17.2(a)).	on No d in this National Stage
2) 🔲 Notic 3) 🔯 Inform	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO/SB/08) r No(s)/Mail Date <u>09/27/2004</u> .	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal Pa	te

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DETAILED ACTION

Claim Rejections - 35 USC § 112

1. The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

2. Claims 10-12 are rejected under 35 U.S.C 112, second paragraph, as being indefinite, vague, and confusing for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention, for example.

It is not clear whether "a (110)- cut rod is useda pump beam as a gain aperture ... a composite material doped YAG is surrounded by undoped YAG ..." are part of the same crystal or independent element working and affecting the crystal. There was no figure to show such structure and/or relationship. There is insufficient means plus function structural relationship between the elements, which render the claims vague and indefinite.

Claim Rejections - 35 USC § 102

- 3. The following is a quotation of 35 U.S.C. 102(b) which forms the basis for all obviousness rejections set forth in this Office action:
 - (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 4. Claims 4, 5, 7 are rejected under 35 U.S.C. 102(a) as being unpatentable Kimura et al. (US 5843227).

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With respect to claim 4, Kimura et al. '227 shows and discloses an optical device (ABSTRACT: GaN crystal superior in flatness crystalline) wherein a direction of beam propagation is selected to be other than those of the (111)-axis direction of a crystal belonging to equi-axis crystal system to reduce birefringence effects based on photoelastic effects due to centrosymmetrically induced stress (Fig 1: shows equi-axis crystal surface direction in direction ([1,0,0], [0,0,1],[0,1,0],[0,-1,0],[0,-1,1]) other than (111) and no birefringence/double refraction due to centrosymmetrically induced stress).

With respect to claim 5 (Fig 1: [1,0,0]) shows wherein the direction of beam propagation is selected to (100)-direction of crystal.

With respect to claim 7, Kimura et al. '227 shows and discloses wherein the crystal in equi-axis crystal system is GaN, or GaAs (ABSTRACT).

Claim Rejections - 35 USC § 103

- 5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

1. Determining the scope and contents of the prior art.

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- 2. Ascertaining the differences between the prior art and the claims at issue.
- 3. Resolving the level of ordinary skill in the pertinent art.
- 4. Considering objective evidence present in the application indicating obviousness or non-obviousness.
- 6. Claims 6 are rejected under 35 U.S.C. 102(a) as being unpatentable Kimura et al. (US 5843227) in view of Sugawara et al. (JP 2001-235775).

With respect to claim 6, Kimura et al. '227 shows and discloses the above (Fig 1: shows GaN crystal superior in flatness crystalline surface direction in direction ([1,0,0], [0,0,1],[0,1,0],[0,-1,0],[0,-1,1]) without discretely disclose propagation in the (110) direction. It has been held where omission of an element/ function in a combination where the remaining elements perform the same function as before involves only routine skill in the art. In this case, the direction of beam propagation is selected to (110)-direction of crystal. Sugawara et al. '775 shows and disclose a crystal is prepared such that the propagation is in the (110) direction (ABSTRACT) (Fig 1: 10, [110] direction).

With respect to claims 8-12 the claims further require wherein a linearly polarized beam forming an angle of 45 ± 5^0 with respect to the crystal axis in a (100)-plane, a composite material in which doped YAG, and wherein a (110)-cut rod and a pump beam which plays a role as a gain aperture are used in a case of end pumping to reduce depolarization when $r_a=r_0/4$, in which r_a is a radius of a laser beam and r_0 is a rod radius. Sugawara et al. '775 shows and disclose a crystal is prepared such that the propagation is in the (110) direction (ABSTRACT) (Fig 1: 10, where crystal axis cut rod [110] direction, where it is a YAG laser [0002], where a pump beam with aperture used in end pumping) (Fig 3, 5: 16,19, 10 where laser beam having a radius and the

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rod another radius) (Fig 4). It has been held where general conditions of a claim are disclosed in the prior art, discovering the optimal ranges involves only routine skill in the art, in this case

 $r_a = r_0/4$.

Communication Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tuan N Nguyen whose telephone number is (571) 272-1948. The examiner can normally be reached on M-F: 7:30 - 4:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Harvey Minsun can be reached on (571) 272-1835. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Tuan N. Nguyen

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